

POSITIVE VOLTAGE REGULATOR

3-TERMINAL 0.1A POSITIVE VOLTAGE REGULATORS

IL78Lxx

This series of fixed-voltage monolithic integrated-circuit voltage regulators is designed for a wide range of applications. These applications include on-card regulation for elimination of noise and distribution problems associated with single-point regulation. In addition, they can be used with power-pass elements to make high current voltage regulators. Each of these regulators can deliver up to 100mA output current.

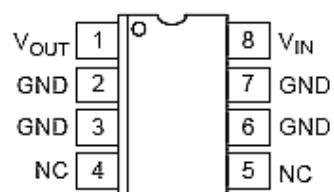
The internal limiting and thermal shutdown features of these regulators make them essentially immune to overload.

When used as a replacement for a zener diode-resistor combination, an effective improvement in output impedance can be obtained together with lower-bias current.

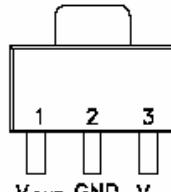
Features

- Output current Up to 100mA
- No External Components
- Internal Thermal Overload Protection
- Internal Short-Circuit Limiting
- Output Voltage of 5V, 6V, 8V, 9V, 10V, 12V, 15V, 18V and 24V

Pin Configuration

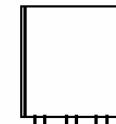


SO-8

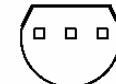


SOT-89

TO-92



1. Output
2. Ground
3. Input



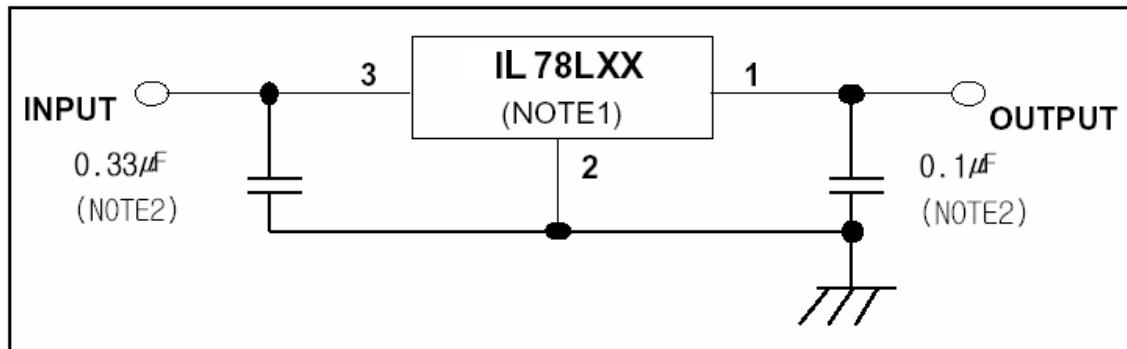
Absolute Maximum Ratings

Characteristic	Symbol	Value	Unit
Input voltage	VI	30	V
		35	
		40	
Operating junction temperature	T _{opr}	-40 ~ +150	°C
Storage temperature	T _{stg}	-65 ~ +150	
Soldering temperature and time	T _{sol}	260/10sec	

RECOMMENDED OPERATING CONDITIONS

78Lxx		Min.	Max.	Unit
Input voltage, VI	IL78L05	7	20	V
	IL78L06	8	20	
	IL78L08	10.5	23	
	IL78L09	11.5	24	
	IL78L10	12.5	25	
	IL78L12	14.5	27	
	IL78L15	17.5	30	
	IL78L18	20.5	33	
	IL78L24	26.5	39	
Output current, IO			100	mA
Operating virtual junction temperature, Tj		-40	125	°C

TYPICAL APPLICATION



Notes

1. To specify an output voltage, substitute voltage for "XX"
2. Bypass capacitors are recommended for optimum stability and transient response and should be located as close as possible to the regulators.

IL78L05 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, $VI=10V$, $Io=40mA$ (unless otherwise noted)

Characteristic	Symbol	Test condition *		Min	Typ.	Max.	Unit
Output voltage **	Vout	25°C		4.8	5	5.2	V
		$1mA \leq Io \leq 40mA$ $7V \leq VI \leq Vmax$		4.75	5	5.25	
		$1mA \leq Io \leq 70mA$		4.75	5	5.25	
Line regulation	Reg line	7 ≤ VI ≤ 20V		25°C	32	150	mV
		8 ≤ VI ≤ 20V			26	100	
Load regulation	Reg load	$1mA \leq Io \leq 100mA$		25°C	15	60	mV
		$1mA \leq Io \leq 40mA$			8	30	
Bias current	IB			25°C	3.8	6	mA
				125°C		5.5	
Bias current change	ΔIB	9 ≤ VI ≤ 20V		-40 ~ 125 °C		1.5	mA
		$1mA \leq Io \leq 40mA$				0.1	
Output noise voltage	V _N	10Hz ≤ f ≤ 100kHz		25°C	42		µV
Ripple rejection	RR	8 ≤ VI ≤ 20V f=120Hz		25°C	41	49	dB
Dropout voltage	V _D			25°C	1.7		V

Notes

- *. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a $0.33\mu F$ capacitor across the input and a $0.1\mu F$ capacitor across the output.

- **. This specification applies only for DC power dissipation permitted by absolute maximum ratings.

IL78L06 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, $VI=12V$, $Io=40mA$ (unless otherwise noted)

Characteristic	Symbol	Test condition *		Min	Typ.	Max.	Unit
Output voltage **	V _{out}		25°C	5.75	6	6.25	V
		1mA ≤ Io ≤ 40mA 8V ≤ VI ≤ 20V	-40 ~ 125°C	5.7	6	6.3	
		1mA ≤ Io ≤ 70mA		5.7	6	6.3	
Line regulation	Reg line	8 ≤ VI ≤ 20V	25°C		35	175	mV
		9 ≤ VI ≤ 20V			29	125	
Load regulation	Reg load	1mA ≤ Io ≤ 100mA	25°C		16	80	mV
		1mA ≤ Io ≤ 40mA			9	40	
Bias current	I _B		25°C		3.9	6	mA
			125°C			5.5	
Bias current change	△I _B	9 ≤ VI ≤ 20V	-40 ~ 125°C			1.5	mA
		1mA ≤ Io ≤ 40mA				0.1	
Output noise voltage	V _N	10Hz ≤ f ≤ 100kHz	25°C		46		μV
Ripple rejection	RR	9 ≤ VI ≤ 19V f=120Hz	25°C	40	48		dB
Dropout voltage	V _D		25°C		1.7		V

Notes

- *. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.
Thermal effects must be taken into account separately.
- All characteristics are measured with a $0.33\mu F$ capacitor across the input and a $0.1\mu F$ capacitor across the output.
- **. This specification applies only for DC power dissipation permitted by absolute maximum ratings.

IL78L08 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, $VI=14V$, $Io=40mA$ (unless otherwise noted)

Characteristic	Symbol	Test condition *		Min	Typ.	Max.	Unit
Output voltage **	V _{out}		25°C	7.7	8	8.3	V
		$1mA \leq Io \leq 40mA$ $10.5V \leq VI \leq 23V$	-40 ~ 125°C	7.6	8	8.4	
		$1mA \leq Io \leq 70mA$		7.6	8	8.4	
Line regulation	Reg line	$10.5 \leq VI \leq 23V$	25°C		42	175	mV
		$11 \leq VI \leq 23V$			36	125	
Load regulation	Reg load	$1mA \leq Io \leq 100mA$	25°C		18	80	mV
		$1mA \leq Io \leq 40mA$			10	40	
Bias current	I _B		25°C		4	6	mA
			125°C			5.5	
Bias current change	ΔI_B	$11 \leq VI \leq 23V$	-40 ~ 125°C			1.5	mA
		$1mA \leq Io \leq 40mA$				0.1	
Output noise voltage	V _N	$10Hz \leq f \leq 100kHz$	25°C		54		µV
Ripple rejection	RR	$13 \leq VI \leq 23V$ $f=120Hz$	25°C	37	46		dB
Dropout voltage	V _D		25°C		1.7		V

Notes

- *. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.
Thermal effects must be taken into account separately.
- All characteristics are measured with a $0.33\mu F$ capacitor across the input and a $0.1\mu F$ capacitor across the output.
- **. This specification applies only for DC power dissipation permitted by absolute maximum ratings.

IL78L09 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, $VI=14V$, $Io=40mA$ (unless otherwise noted)

Characteristic	Symbol	Test condition *		Min	Typ.	Max.	Unit
Output voltage **	V _{out}		25°C	806	9	9.4	V
		1mA ≤ Io ≤ 40mA 12V ≤ VI ≤ 24V	-40 ~ 125°C	8.55	9	9.45	
		1mA ≤ Io ≤ 70mA		8.55	9	9.45	
Line regulation	Reg line	12 ≤ VI ≤ 24V	25°C		45	175	mV
		13 ≤ VI ≤ 24V			40	125	
Load regulation	Reg load	1mA ≤ Io ≤ 100mA	25°C		19	90	mV
		1mA ≤ Io ≤ 40mA			11	40	
Bias current	I _B		25°C		4.1	6	mA
			125°C			5.5	
Bias current change	ΔI _B	13 ≤ VI ≤ 24V	-40 ~ 125°C			1.5	mA
		1mA ≤ Io ≤ 40mA				0.1	
Output noise voltage	V _N	10Hz ≤ f ≤ 100kHz	25°C		58		μV
Ripple rejection	RR	13 ≤ VI ≤ 23V f=120Hz	25°C	38	45		dB
Dropout voltage	V _D		25°C		1.7		V

Notes

- *. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a $0.33\mu F$ capacitor across the input and a $0.1\mu F$ capacitor across the output.

- **. This specification applies only for DC power dissipation permitted by absolute maximum ratings.

IL78L10 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, $VI=16V$, $Io=40mA$ (unless otherwise noted)

Characteristic	Symbol	Test condition *		Min	Typ.	Max.	Unit
Output voltage **	V _{out}		25°C	9.6	10	10.4	V
		1mA ≤ Io ≤ 40mA 13V ≤ VI ≤ 25V	-40 ~ 125°C	9.5	10	10.5	
		1mA ≤ Io ≤ 70mA		9.5	10	10.5	
Line regulation	Reg line	13 ≤ VI ≤ 25V	25°C		51	175	mV
		14 ≤ VI ≤ 25V			42	125	
Load regulation	Reg load	1mA ≤ Io ≤ 100mA	25°C		20	90	mV
		1mA ≤ Io ≤ 40mA			11	40	
Bias current	I _B		25°C		4.2	6	mA
			125°C			5.5	
Bias current change	△I _B	14 ≤ VI ≤ 25V	-40 ~ 125°C			1.5	mA
		1mA ≤ Io ≤ 40mA				0.1	
Output noise voltage	V _N	10Hz ≤ f ≤ 100kHz	25°C		62		μV
Ripple rejection	RR	15 ≤ VI ≤ 25V f=120Hz	25°C	37	44		dB
Dropout voltage	V _D		25°C		1.7		V

Notes

- *. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a $0.33\mu F$ capacitor across the input and a $0.1\mu F$ capacitor across the output.

- **. This specification applies only for DC power dissipation permitted by absolute maximum ratings.

IL78L12 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, $VI=17V$, $Io=40mA$ (unless otherwise noted)

Characteristic	Symbol	Test condition *		Min	Typ.	Max.	Unit
Output voltage **	V _{out}		25°C	11.5	12	12.5	V
		1mA ≤ Io ≤ 40mA 14V ≤ VI ≤ 27V	-40 ~ 125°C	11.4	12	12.6	
		1mA ≤ Io ≤ 70mA		11.4	12	12.6	
Line regulation	Reg line	14.5 ≤ VI ≤ 27V	25°C		55	250	mV
		16 ≤ VI ≤ 27V			49	200	
Load regulation	Reg load	1mA ≤ Io ≤ 100mA	25°C		22	100	mV
		1mA ≤ Io ≤ 40mA			13	50	
Bias current	I _B		25°C		4.3	6.5	mA
			125°C			6	
Bias current change	ΔI _B	16 ≤ VI ≤ 27V	-40 ~ 125°C			1.5	mA
		1mA ≤ Io ≤ 40mA				0.1	
Output noise voltage	V _N	10Hz ≤ f ≤ 100kHz	25°C		70		µV
Ripple rejection	RR	15 ≤ VI ≤ 25V f=120Hz	25°C	37	42		dB
Dropout voltage	V _D		25°C		1.7		V

Notes

- *. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a $0.33\mu F$ capacitor across the input and a $0.1\mu F$ capacitor across the output.

- **. This specification applies only for DC power dissipation permitted by absolute maximum ratings.

IL78L15 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, $VI=19V$, $Io=40mA$ (unless otherwise noted)

Characteristic	Symbol	Test condition *		Min	Typ.	Max.	Unit
Output voltage **	V _{out}		25°C	14.4	15	15.6	V
		1mA ≤ Io ≤ 40mA 17.5V ≤ VI ≤ 30V	-40 ~ 125°C	14.25	15	15.75	
		1mA ≤ Io ≤ 70mA		14.25	15	15.75	
Line regulation	Reg line	17.5 ≤ VI ≤ 30V	25°C		65	300	mV
		19 ≤ VI ≤ 30V			58	250	
Load regulation	Reg load	1mA ≤ Io ≤ 100mA	25°C		25	150	mV
		1mA ≤ Io ≤ 40mA			15	75	
Bias current	I _B		25°C		4.2	6.5	mA
			125°C			6	
Bias current change	△I _B	19 ≤ VI ≤ 30V	-40 ~ 125°C			1.5	mA
		1mA ≤ Io ≤ 40mA				0.1	
Output noise voltage	V _N	10Hz ≤ f ≤ 100kHz	25°C		82		μV
Ripple rejection	RR	18.5 ≤ VI ≤ 28.5V f=120Hz	25°C	37	44		dB
Dropout voltage	V _D		25°C		1.7		V

Notes

- *. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a $0.33\mu F$ capacitor across the input and a $0.1\mu F$ capacitor across the output.

- **. This specification applies only for DC power dissipation permitted by absolute maximum ratings.

IL78L18 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, $VI=23V$, $Io=40mA$ (unless otherwise noted)

Characteristic	Symbol	Test condition *		Min	Typ.	Max.	Unit
Output voltage **	V _{out}		25°C	17.3	18	18.7	V
		$1mA \leq Io \leq 40mA$ $20.5V \leq VI \leq 33V$	-40 ~ 125°C	17.1	18	18.9	
		$1mA \leq Io \leq 70mA$		17.1	18	18.9	
Line regulation	Reg line	$20.5 \leq VI \leq 33V$	25°C		70	360	mV
		$22 \leq VI \leq 33V$			64	300	
Load regulation	Reg load	$1mA \leq Io \leq 100mA$	25°C		27	180	mV
		$1mA \leq Io \leq 40mA$			19	90	
Bias current	I _B		25°C		4.7	6.5	mA
			125°C			6	
Bias current change	ΔI_B	$22 \leq VI \leq 33V$	-40 ~ 125°C			1.5	mA
		$1mA \leq Io \leq 40mA$				0.1	
Output noise voltage	V _N	$10Hz \leq f \leq 100kHz$	25°C		82		µV
Ripple rejection	RR	$21.5 \leq VI \leq 31.5V$ $f=120Hz$	25°C	32	36		dB
Dropout voltage	V _D		25°C		1.7		V

Notes

- *. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a $0.33\mu F$ capacitor across the input and a $0.1\mu F$ capacitor across the output.

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IL78L24 ELECTRICAL CHARACTERISTICS

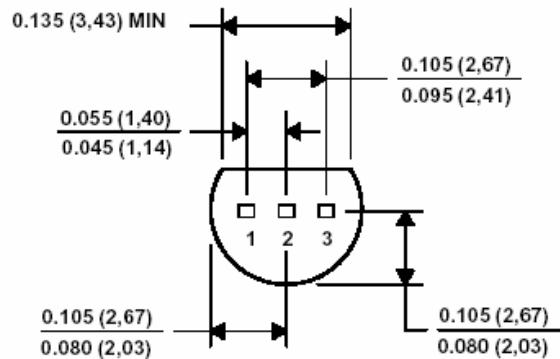
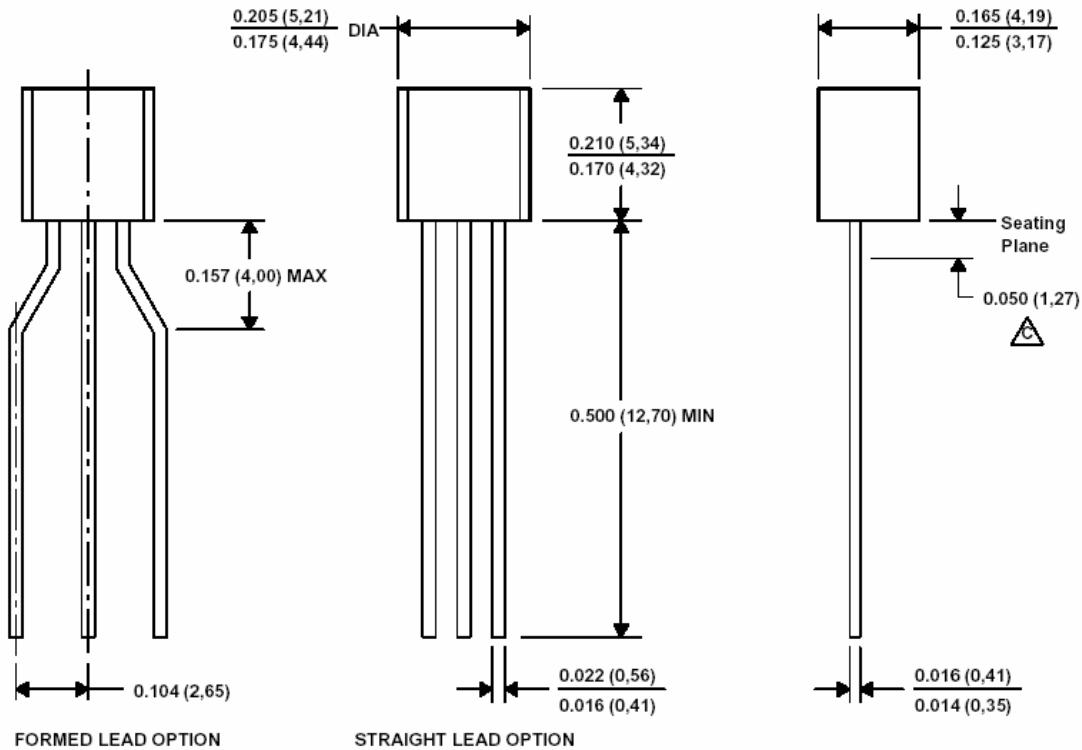
(At specified virtual junction temperature, $VI=26V$, $Io=40mA$ (unless otherwise noted)

Characteristic	Symbol	Test condition *		Min	Typ.	Max.	Unit
Output voltage **	Vout		25°C	23	24	25	V
		$1mA \leq Io \leq 40mA$ $26.5V \leq VI \leq 39V$	-40 ~ 125°C	22.8	24	25.2	
		$1mA \leq Io \leq 70mA$		22.8	24	25.2	
Line regulation	Reg line	$26.5 \leq VI \leq 39V$	25°C		95	480	mV
		$29 \leq VI \leq 39V$			78	400	
Load regulation	Reg load	$1mA \leq Io \leq 100mA$	25°C		41	240	mV
		$1mA \leq Io \leq 40mA$			28	120	
Bias current	I_B		25°C		4.8	6.5	mA
			125°C			6	
Bias current change	ΔI_B	$28 \leq VI \leq 39V$	-40 ~ 125°C			1.5	mA
		$1mA \leq Io \leq 40mA$				0.1	
Output noise voltage	V_N	$10Hz \leq f \leq 100kHz$	25°C		82		µV
Ripple rejection	RR	$27.5 \leq VI \leq 37.5V$ $f=120Hz$	25°C	30	33		dB
Dropout voltage	V_D		25°C		1.7		V

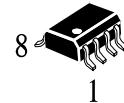
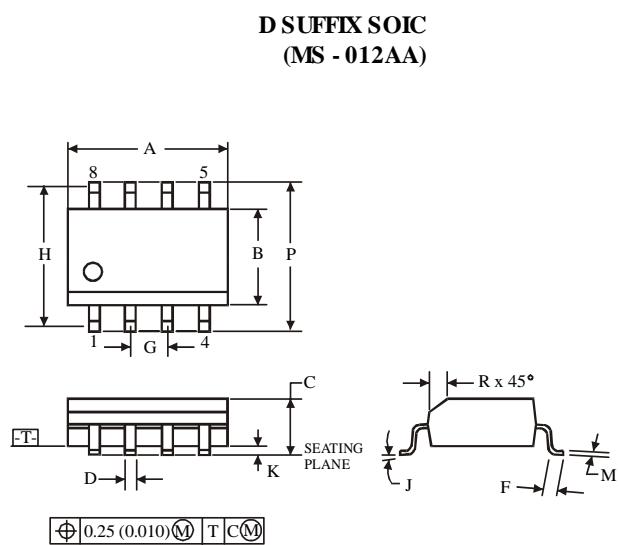
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- All characteristics are measured with a $0.33\mu F$ capacitor across the input and a $0.1\mu F$ capacitor across the output.
- **. This specification applies only for DC power dissipation permitted by absolute maximum ratings.

• TO-92



- SO-8

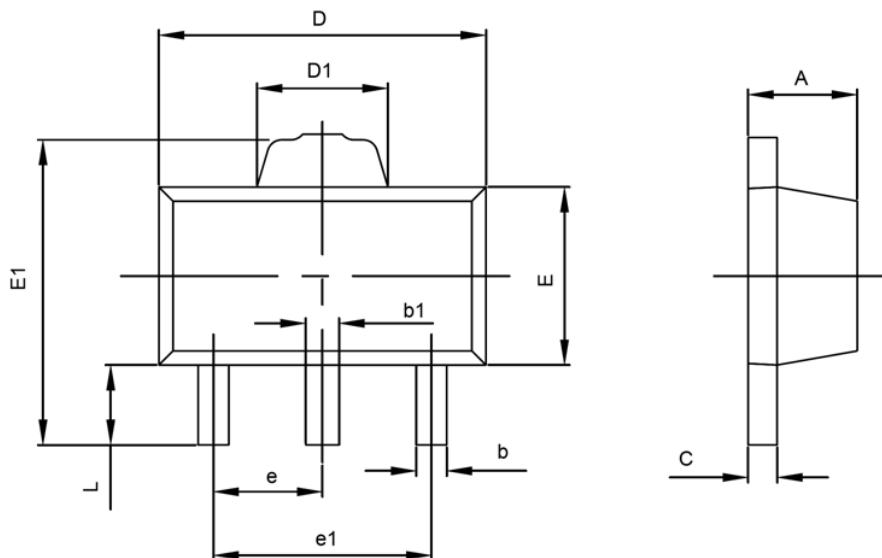


	Dimension, mm	
Symbol	MIN	MAX
A	4.8	5
B	3.8	4
C	1.35	1.75
D	0.33	0.51
F	0.4	1.27
G	1.27	
H	5.72	
J	0°	8°
K	0.1	0.25
M	0.19	0.25
P	5.8	6.2
R	0.25	0.5

NOTES:

1. Dimensions A and B do not include mold flash or protrusion.
2. Maximum mold flash or protrusion 0.15 mm (0.006) per side for A; for B - 0.25 mm (0.010) per side.

SOT-89-3L PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.400	1.600	0.055	0.063
b	0.320	0.520	0.013	0.020
b1	0.360	0.560	0.014	0.022
c	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.400	1.800	0.055	0.071
E	2.300	2.600	0.091	0.102
E1	3.940	4.250	0.155	0.167
e	1.500TYP		0.060TYP	
e1	2.900	3.100	0.114	0.122
L	0.900	1.100	0.035	0.043